VIBRATIONAL SPECTRA AND STRUCTURAL STUDIES OF Hg-As-S GLASSES

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Structural interpretation of Raman and IR spectra, and X-ray diffraction study give evidence to the fact that the adding of mercury into binary glass-forming system causes the formation of α -HgS and β -As₄S₄ at $C_{\rm Hg} > 2$ at.%. Slow quenching of the melt of HgAsS₂ compound results in the separation of α -HgS and β -As₄S₄. In the chain-like model of a-As₂S₃ structure, the addition of Hg atoms results in the increase of chain dimensions from 1.42 to 1.8 nm.

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1. Introduction

In a binary As-S system, the composition As_2S_3 exists in crystalline (c) and in amorphous (a) form [1]. In layered c- As_2S_3 , each arsenic atom is bonded with three sulphur atoms, forming a pyramid with arsenic atom at the apex. In each layer, the atoms are arranged in the order S-As-S-As and form a spiral which produces a chain due to the translation parallel to the spiral axis. Such spiral chains are parallel one to another and to the c-axis [2-4]. The results of several diffraction measurements confirm the presence of the short-range crystalline order in amorphous a-As₂S₃ [3,5-7]. On this base, a new type of order was defined: the medium-range order (MRO), known as the intermediate-range range order (IRO) [8-11]. There is also evidence that the medium-range order of this glass involves neighbouring pyramids of AsS₃ and their shared atom of sulphur [11]. The vibrational spectra of the system of interconnected clusters based on AsS_{3/2} structural units (s.u.) in the region of valence vibrations is similar to that of bulk glass a-As₂₂S₇₈ [12]. In

the chain-like approximation, the average correlation length of clusters (MRO) in $a-As_2S_3$ is 1.42 nm [12].

The introduction of additives into the As-S system causes the variation in some important physical characteristics [2,13]. This allows one to improve the properties of materials which are important for their application in coherent optoelectronics and laser-technology devices [14]. Among the chalcogenide materials with bivalency additives, the glasses of the Hg-As-S system are of particular importance. In this system, a ternary HgAsS₂ compoud, a natural mineral halchaite, is known [15]. Since structural peculiarities of Hg-As-S glasses have not been properly studied yet, the investigation of the vibrational spectra of these materials is of special interest.

We present the studies of the changes in far infrared (IR) and Raman spectra, edge absorption and sound velocity of glasses of the Hg-As-S system of compositions close to $\mathrm{As_2S_3}$.

2. Experimental

The Raman spectra of the glasses were taken with the spectrophotometer DFS-24. The velocity of ultrasound was measured by the echo method. The absorption edge was estimated from the transmission and reflection data for samples up to 5 cm in size. The multiple reflections were also taken into account. Far IR spectra were taken using a FIS-3 spectrophotometer. The glasses were synthetized using the methods similar to those described in Ref. 4. For the X-ray diffraction analysis of powder of the glasses, the widespead method was used. The dimensions of chain-like fragments (L) were calculated using the relation [17]:

$$L = \frac{I}{2 c \omega_B} \sqrt{E/\rho},$$

where E is the calculated value of the Young's modulus, ρ the measured density of the glass, ω_B the low-frequency maximum in the Raman spectra and c is the velocity of light.

3. Results and discussion

We have started the structural interpretation of vibrational spectra od Hg-As-S glasses by considering the spectrum of a-As₂S₃ (Fig. 1, curve 1). The profile of the $250-400~\rm cm^{-1}$ absorption envelope of this glass suggests the existence of three main component bands at 310, 342 and 380 cm⁻¹. In the first approximation, the assignment of these bands can be made on the basis of the molecular model proposed in Ref. 20 for the interpretation of the vibrational spectra of glasses of type As₂X₃ (X = S, Se, Te). This model considers the modes of vibrationally decoupled AsX₃ pyramid and As-X-As "water-like" bridging bonds. Thus, in terms of the molecular model, the stronger band at 310 cm⁻¹ is assigned to the asymmetric mode

 $\nu_3({\rm E})$ of AsS₃ pyramidal s.u., while the one at 342 cm⁻¹ to the symmetric stretching mode $\nu_1({\rm A}_1)$ s.u. The high frequency component at 380 cm⁻¹ is attributed to the asymmetric stretching vibration of the As-S-As bridges. These assignments are consistent with the Raman spectrum of a-As₂S₃, which shows strong scattering at $\nu_1({\rm A})=342~{\rm cm}^{-1}$, weaker feature at $\nu_3({\rm E})=310~{\rm cm}^{-1}$ and a shoulder at 375 cm⁻¹ [20].

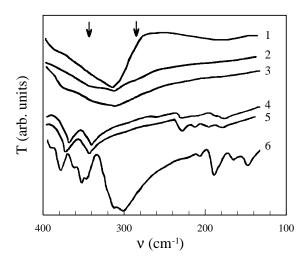


Fig. 1. Far infrared spectra of Hg-As-S glasses: $1-a\text{-}As_2S_3$, $2-Hg_5As_{38}S_{57}$, $3-Hg_{10}As_{36}S_{54}$, $4-Hg_5As_{50}S_{45}$, $5-As_{50}S_{50}$, $6-c\text{-}As_2S_3$. The arrows indicate the positions of bands in IR spectrum of $\alpha\text{-}HgS$.

If adding 5 or 10 at.% of Hg into a-As₂S₃, new shoulders near 340 and 290 cm⁻¹ appear in IR spectra of the ternary glasses (Fig. 1, curves 2 and 3). In Ref. 21, it was reported that the corresponding strongest bands of α -HgS are at 345 and 284 cm⁻¹ [21] (in Figs. 1 and 3, the arrows indicate the positions of bands in IR spectrum of α -HgS). Such peculiarities are not revealed in the Raman spectra because the frequencies of the main bands of Raman spectra of α -HgS are close to the vibration band ν_1 (a) of AsS_{3/2} s.u. [20]. But at $C_{\rm Hg} = 5$ at.%, in Raman spectra of ternary glass (Fig. 1, curve 1), the bands typical of β -As₄S₄ (at 182, 222 and 360 cm⁻¹) [18] begin to appear (Fig. 2, curve 2). When $C_{\rm Hg} = 7$ at.%, the latter three typical bands of β -As₄S₄ are clearly observed in Raman spectra of ternary glass (Fig. 2, curve 1). Similar situation in transformation Raman spectra was observed in Ref. 17 after adding a small (1 – 5 at.%) content of Ge into As₂S₃.

These typical bands of β -As₄S₄ are clearly seen in the IR spectrum of materials whose composition is corresponding to HgAsS₂ compound (Fig. 3, curve 1).

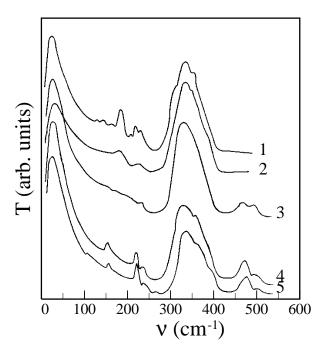


Fig. 2. Raman spectra of Hg-As-S glasses: $1-\mathrm{Hg_7As_{40}S_{53}},\ 2-\mathrm{Hg_5As_{38}S_{57}},\ 3-\mathrm{Hg_{2.4}As_{29.2}S_{68.4}},\ 4-\mathrm{Hg_2As_{29.6}S_{68.4}},\ 5-\mathrm{Hg_4As_{22.2}S_{73.8}}.$

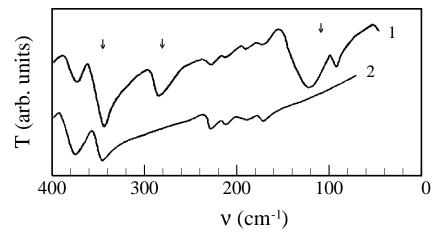


Fig. 3. Far infrared spectra of Hg-As-S₂ (curve 1) and $As_{50}S_{50}$ (curve 2). The arrows indicate the positions of bands in IR spectrum of α -HgS.

In Ref. 21, the bonding energy of α -HgS was determined from X-ray photoelectron spectra (XPS) of ternary glassy Hg-As-S near As₂S₃ ($C_{\rm Hg}>2$ at.%). The

analysis of XPS spectra of ternary glasses with $C_{\rm Hg} < 2$ at.% reveals that mercury is present mainly in elementary form.

We have also taken into account data on differential-thermal treatment (DTT) [21] and X-ray diffraction analysis of ternary glasses of corresponding composition but in powder form. In accordance with the diffraction data for ternary glasses ($C_{\rm Hg} > 2$ at.%), both crystalline phases, β -As₄S₄ and α -Hg-S, appear.

One may suppose that the reaction

$$As_2S_3 + x Hg \rightarrow (1-x) As_2S_3 + x \alpha - HgS + \beta - As_4S_4$$

takes place. This is confirmed by the structural data obtained from structural interpretation of vibrational spectra (Figs. 1 and 2), data from X-ray diffraction and XPS spectral analyses [21].

It should be mentioned that according to the far IR spectra and X-ray analysis, the direct synthesis in quartz ampoules of elementary As, S and Hg, whose composition corresponds to HgAsS₂ compound (halchaite) [15] and subsequent quenching of the melt in air (10^{-2} K/s) results in the formation of microheterogeneous mixture of β -As₄S₄ and α -HgS crystals (see Fig. 3).

Thus, the formation of stable glasses in the Hg-As-S system under slow quenching (10^{-2} K/s) takes place on the basis of the $\text{AsS}_{3/2}$ glass-forming s.u. only. The analysis of the change of ultrasound velocity (Fig. 4), and the effect of adding more than 2 at.% of Hg into the binary As-S system, corresponds well to the data on diffraction and X-ray analysis, which show that chalcogen reaction with Hg is energetically more favourable than the one with arsenic. That is why adding more than 2 at.% of metal into the mixture results in the formation of chalcogenides of Hg

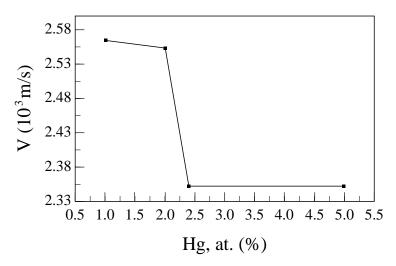


Fig. 4. Concentration dependence of longitudinal sound velocity (V) of Hg-As-S glasses (points left to right): Hg₁As_{39.2}S_{59.8}, Hg₂As_{38.6}S_{59.4}, Hg_{2.4}As_{29.2}S_{68.4}, Hg₅As₃₈S₅₇.

with a large ionic component of chemical bond. They form α -HgS when the content of Hg exceeds 2 at.% [21].

Figure 5 shows the influence of Hg on the energy dependence of edge absorption of Hg-As-S glasses in the region of low values of α . For glasses of similar composition to As₂S₃, but with 2 to 5 at.% of Hg, a nonmonotonic shift of the absorption edge to a low-energy region is observed. Besides, with respect to a pure a-As₂S₃ with an increasing Hg content, the increase of the absorption in the region from 10^{-1} to $1.0~\rm cm^{-1}$ takes place. Such changes of the character of the absorption edge in ternary Hg-As-S glasses may be related to the formation of continuously increasing occurence of Hg-S and As-S bonds, typical for α -HgS and β -As₄S₄ compounds with increasing contents of Hg. The increase of light losses in this low absorption region may be related to the scattering of light by microcrystalline centres of sizes of about 10 nm [10]. A similar situation takes place in the Ag-As-S system where AgS microcrystals are formed [19].

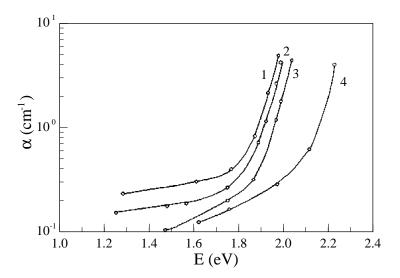


Fig. 5. Dependence of edge absorption on concentration of Hg-As-S glasses: $1 - \text{Hg}_5\text{As}_{38}\text{S}_{57}, \ 2 - \text{Hg}_2\text{As}_{39.5}\text{S}_{58.5}, \ 3 - \text{a-As}_2\text{S}_3, \ 4 - \text{Hg}_{0.4}\text{As}_{22.2}\text{S}_{77.4}.$

The shift in Boson maximum from $w_{\rm B}=26~{\rm cm^{-1}}$ at $C_{\rm Hg}=0$ [12] to $w_{\rm B}=19~{\rm cm^{-1}}$ at $C_{\rm Hg}=5$ at.% in Hg-As-S glasses (Fig. 2) is an evidence to the change in the structure compactness [22]. The calculations similar to those described in Ref. 12 show that such changes in the chain-like approximation cause the increse of the length of the chains, which consist of ${\rm AsS_{3/2}}$ pyramids, from $L=1.43~{\rm nm}$ (a-As₂S₃ [12]) to $L=1.89~{\rm nm}$ at $C_{\rm Hg}=5~{\rm at.\%}$. In the chain-like approximation, the breaking of the structure matrix by the introducing Hg atoms into a-As₂S₃ causes the decrease in the interchain interaction at $C_{\rm Hg}>2~{\rm at.\%}$.

4. Conclusion

When one adds more than 2 at.% of mercury to a-As₂S₃, the bands typical for α -HgS begin to separate in the IR spectra of Hg-As-S glasses. One observes the change of the position of the low-frequency maximum and an increase of the absorption coefficient α in the region 10^{-1} to $1.0~\rm cm^{-1}$ of the absorption edge, and the length of the chains increases from 1.42 nm for As₂S₃ to 1.8 nm for Hg-As-S glasses along the Hg-As₂S₃ and HgS-As₂S₃ sections.

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SPEKTRI VIBRACIJA I PROUČAVANJE STRUKTURE STAKALA Hg-As-S

Objašnjenje strukture na osnovi Ramanovih i infracrvenih spektara i proučavanje difrakcije X zračenja pokazuju da dodavanje Hg u binarni staklasti As-S uzrokuje stvaranje α -HgS i β -As₄S₄ pri $C_{\rm Hg}>2$ at.%. Sporim kaljenjem taljevine HgAsS₂ dolazi do razdvajanja α -HgS i β -As₄S₄. U lančastom modelu strukture a-As₂S₃, dodavanje Hg uzrokuje porast duljine lanaca od 1.42 na 1.8 nm.